

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



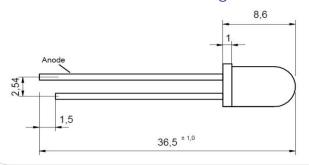


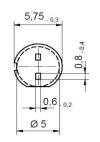




Product No: MTE0012-525-IR

Peak Emission Wavelength: 1200nm





Description

- Standard 5mm plastic lens package housed without standoff leads
- Type: MQW
- High power
- High speed infrared

Application

- Optical communication
- Safety equipment
- Automation

Absolute Maximum Ratings (Ta=25°C)					
ITEMS	TEST CONDITIONS	SYMBOL	RATINGS	UNIT	lead-free ROHS
Forward DC Current		If	100	mA	
Peak Forward Current	$(tp \le 50us, tp/T=1/2)$	Ifp	200	mA	
Power Dissipation		Pd	150	mW	
Operating Temperature Range		Тор	-20 to +80	°C	
Storage Temperature Range		Tstg	-55 to +100	°C	
Lead Soldering Temperature	t<5s, 3mm from case	Tslg	260	°C	

SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Vf				1.1	V
Vf	If=100mA		1.0	1 .2	V
Vr	Ir=10uA	5			V
Фе	If=20mA	1.1	1.5		mW
Фе	If=100mA		7		mW
λр	If=20mA	1170	1200	1230	nm
Δλ0.5	If=20mA		70		nm
φ	If=20mA		20		deg
tr, tf	If=20mA		25, 40		ns
	Vf Vr Φe Φe λp Δλ0.5	Vf	Vf	Vf If=20mA 0.9 Vf If=100mA 1.0 Vr Ir=10uA 5 Φe If=20mA 1.1 1.5 Φe If=100mA 7 λp If=20mA 1170 1200 $\Delta \lambda 0.5$ If=20mA 70 ϕ If=20mA 20	Vf If=20mA 0.9 1.1 Vf If=100mA 1.0 1.2 Vr Ir=10uA 5 Φe If=20mA 1.1 1.5 Φe If=100mA 7 λp If=20mA 1170 1200 1230 $\Delta \lambda 0.5$ If=20mA 70 φ If=20mA 20